Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-302-8071

Inclosure Material:
Glass
Overall Length:
0.220 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
800.0 reverse voltage, instantaneous
Special Features:
First wire lead Ig is 3.700 in., second lead is 2.300 in. Lg; junction pattern arrangement: pn
Terminal Type And Quantity:
2 insulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

A110a0